



Docket No.: 21737-00013-US  
(PATENT)

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re Patent Application of:  
Katsuki Hazama

Application No.: 09/438,295

Confirmation No.: 9121

Filed: November 12, 1999

Art Unit: 2135

For: MULTILEVEL SEMICONDUCTOR MEMORY WRITE/  
READ METHOD THERETO/THEREFROM AND  
STORAGE MEDIUM STORING WRITE/READ PRO-  
GRAM

Examiner: L. Hua

**CHANGE OF CORRESPONDENCE ADDRESS**

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Dear Sir:

In accordance with the Manual of Patent Examining Procedures, Section 601.03, please  
change the mailing address for all correspondence in the above-identified patent application to:

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Please direct all further communications to the above-identified firm.

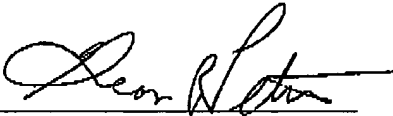
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Applicant believes no fee is due with this response. However, if a fee is due, please charge our Deposit Account No. 22-0185, under Order No. 21737-00013-US from which the undersigned is authorized to draw.

Dated: 12/01/04

Respectfully submitted,

By   
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